SEMICONDUCTOR TECHNICAL DATA

Dual Schottky Barrier Rectifiers Reverse Voltage 100 Volts Forward Current 30.0 Amperes

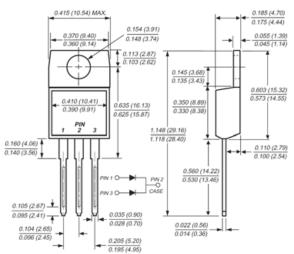
Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
 High temperature soldering guaranteed;
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

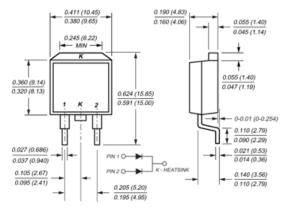
Mechanical Data

- Case: JEDEC TO-220AB, TO-220F, TO-263AB molded plastic body
- Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting Position: Any
- Mounting Torque: 10 in-lbs maximum
- ♦ Weight: 0.08 ounce, 2.24 grams

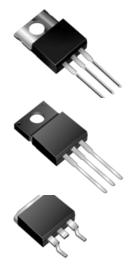
TO-220AB



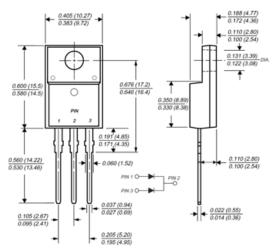
TO-263AB(D²PAK)



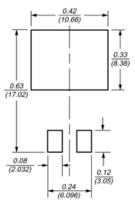
Dimensions in inches and (millimeters)



TO-220F



Mounting Pad Layout TO-263AB







Maximum Ratings and Electrical Characteristics

($T_c = 25^{\circ}C$ unless otherwise noted)

MAXIMUM RATINGS and ELECTRICAL CHARACTERISTICS(TC=25°C unless otherwise moted)							
PARAMETER	TEST C	ONDITIONS	SYMBOL		UNIT		
Maximum repetitive peak reverse voltage			Vrrm	100	V		
Working peak reverse voltage			Vrwm	100	V		
Maximum DC blocking voltage			VDC	100	V		
Maximum average forward rectified current at Tc=105°C total device per diode			lf(AV)	30 15	А		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode			IFSM	250	А		
Peak repetitive reverse current per leg at tp=2.0us , 1KHz			IRRM	1.0	А		
Voltage rate of change (rated VR)			DV/dt	10000	V/us		
Operating junction temperature range			TJ	-65 to+150	°C		
Storage temperature range			TSTG	-65 to+150	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			VAC	1500	V		
Maximum instantaneous forward voltage per leg	IF=15A IF=15A	TC=25℃ TC=125℃	VF	0.85 0.75	V		
Maximum reverse current per leg at working peak Reverse voltage		TJ=25℃ TJ=100°C	IR	500 7	uA mA		

Thermal Characteristics Ta=25 °C unless otherwise noted

Symbol	Parameter	Max	Unit
Rejc	Thermal Resistance, Junction to Case per Leg	4.0	°C /W
Reja	Thermal Resistance, Junction to Ambient per Leg	62.5	°C /W

Note:

1. Screw mounting with 4-40 screw, where washer diameteris≤4.9mm(0.19 ″)

2. Pulse test:300us pulse width,1% duty cycle



Rating and Characteristic Curves

Figure 3

100

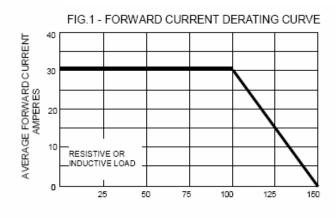
10

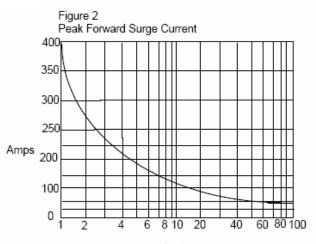
1.0

1

mAmps

Typical Reverse Characteristics

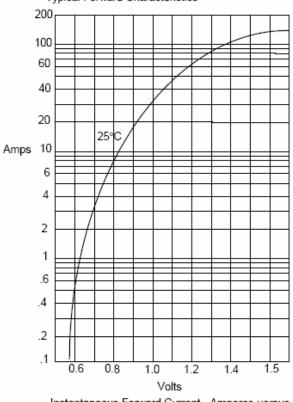




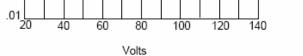
Cycles

Peak Forward Surge Current - Amperes versus Number Of Cycles At 60Hz - Cycles

Figure 4 Typical Forward Characteristics



Instantaneous Forward Current - Amperes versus Instantaneous Forward Voltage - Volts



T_A≠125°C

Instantaneous Reverse Leakage Current - MicroAmperes versus Percent Of Rated Peak Reverse Voltage - Volts

First Silicon